A 71PS-RESOLUTION MULTI-CHANNEL CMOS TIME-TO-DIGITAL CONVERTER FOR POSITRON EMISSION TOMOGRAPHY IMAGING APPLICATIONS

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Keywords: Time-to-Digital Converter (TDC), Delay Locked Loop (DLL), Array of DLL’s, Positron Emission Tomography (PET).

Abstract: This paper presents a high-resolution multi-channel Time-to-Digital Converter (TDC) for Positron Emission Tomography (PET) imaging system. The TDC using a two-level conversion scheme is proposed for obtaining high timing resolution. Double 10-bit gray counters are designed for coarse conversion while a multiphase sampling technology is presented for fine conversion. In order to achieve better timing resolution with either a faster technology, an array of Delay-locked loops is chosen as a timing generator. A prototype chip of 3-channel TDC is designed and fabricated in AMS 0.35µm CMOS technology. The area of the chip is 8.4 mm² in size. The measured range of the TDC is 10µs. The time tap is reduced to 71ps with a reference clock of 100MHz. The differential nonlinearity is ±0.1LSB. The circuits will be extended to 64 channels for small animal PET imaging systems.

1 INTRODUCTION

Positron Emission Tomography (PET), which is a leading imaging technique for the detection of cancer, has been demanded for a non-invasive imaging system for clinical diagnosis by measurement of the metabolic activity (Mbow et al., 2007). The physical principle is based on the detection of gamma radiations resulting from the disintegration of positrons emitted by the radiotracer. A pair of 511keV photon generates from the annihilation of a positron and an electron. The photons (511keV) are emitted in opposite directions and both are absorbed by detector module and converted into an electrical signal. The signal is then amplified and digitized by a serial of readout electronics. By taking a large number of coincident events, many lines can be constructed. An image can then be reconstructed by employing a tomographic algorithm on the data (Mbow et al., 2007), (Brian K. Swann et al., 2004).

The quality of the image is limited both by the efficiency of the used detectors and system resolution including spatial resolution and timing resolution. The improvement of system resolution pushes the processing requirements on both novel detectors and the front-end data acquisition system. Moreover, semiconductor-based scintillators are being investigated which could lead to a detection timing resolution below 100ps (Bourrion and Gallin-Martel, 2006). Such performance requirement is calling for high-resolution time-measurement devices for data acquisition and processing system. A time-to-digital converter (TDC) is one type of an electronic instrumentation system that is capable of measuring the time difference between two random events. The aim of this paper is to develop a 71ps-resolution multi-channel Time-to-digital converter (TDC) to measure the time difference of a pair of 511-keV photons for PET imaging reconstruction. For each channel, the time intervals from the moment that coincidence event occurs to the time that the photons are absorbed by detectors will be measured, registered and converted to digital
Several researchers have reported the design of TDC for PET imaging systems. An integrated CMOS sub-nanosecond TDC has been developed under the aid of flash ADC technology. The time resolution is reported as 312.5ps (Brian K. Swann et al., 2004). In addition, a 224ps-resolution TDC based on DLL technology was reported for liquid Xenon PET (Bourrion and Gallin-Martel, 2006). The prototype chip of such TDC included a single DLL with 128 delay cells. It was difficult to deal with the mismatch of long-chain delay cells. For obtaining smaller time resolution, a new architecture based on a hierarchical delay processing structure was proposed for next generation PET imaging (Yousif and Haslett, 2007). A prototype chip was fabricated in 0.13µm CMOS process and ran at a clock of 500MHz. Although high resolution was obtained, a faster technology was needed due to the high-frequency clock utilized in the chip.

Few studies have been done on development of a TDC that a better resolution obtained by using either a faster technology for PET imaging applications. However, a two-level conversion scheme based on an array of DLLs is a good solution for this challenge. The original proposals of TDC based on array of DLLs have been published in (Christiansen, 1996), (Mota and Christiansen, 1998). A resolution of 89.3ps was realized with a clock frequency of 80MHz (Mota and Christiansen, 1998). In this paper, we present the design of a TDC based-on an array of low-jitter DLLs for PET imaging system. The results agree with the design of TDC’s in (Christiansen, 1996) and (Mota and Christiansen, 1998). The better results are achieved because low-jitter DLLs are employed and the relatively advanced CMOS technology (0.35µm) is utilized. The resolution of 71ps with a clock frequency of 100MHz is obtained from our prototype chip.

In Section 2 of this paper, the principle of measurement and proposed architecture are described. In Section 3, the description of circuits is given. In Section 4, a prototype chip of TDC and experimental results are described. Section 5 concludes the paper.

## 2 OPERATIONAL PRINCIPLE AND PROPOSED ARCHITECTURE

TDC systems are designed to measure the time interval from START to STOP signal. For large time interval, a counter is employed to counter numbers when a reference clock is used. The measured time equates to the counted number multiple by the period of the clock. The resolution of TDC is depended on the period of reference clock. If smaller time tap is needed, a high-frequency clock needs to be employed. Another solution is two-level conversion scheme. The counter is employed for coarse conversion and a multiphase sampling technology is proposed for fine conversion. The multiphase generators are designed to generate multiphase delayed in one period of the reference clock. The state of multiphase will be asserted, registered and converted to binary codes.

A delay-locked loop (DLL) is usually employed as a multiphase generator. In the DLL, the reference clock is propagated through voltage-controlled delay line (VCDL). The output signal at the end of the delay line is compared with the reference clock. If the delay difference from integer multiples of clock period is detected, the closed loop will automatically correct it by changing the delay time of VCDL. A DLL can be locked to one clock if the initial delay of VCDL is located between 0.5Tclk and 1.5 Tclk (Chang et al., 2002).

Figure 1 shows the operational principle of TDC for small animal PET imaging system. The system is reset with a cycle period of 10µs. The reset signal, so called as Hit clear in Figure 1, is the START signal of TDC. A “Hit” signal generated by external pulse of an event is the STOP signal. The time interval between the falling edge of Hit clear and the rising edge of Hit are measured by TDC chip. In coarse conversion level, a counter is utilized to count numbers. The counter commences to count at the falling edge of Hit clear and is interrupted while a rising edge of “Hit” signal arrives. The last number is read out as coarse data. In fine conversion step, the delayed clock is generated by multiphase generator. The state of the multiphase is readout by rising edge of Hit signal. The acquisition data is then converted to binary code. The total time can be described as,

\[ T_{tdc} = N_c \times T_{ref} + N_f \times T_{bin} \]  

Where, \( T_{tdc} \) is the total time measured by TDC; \( N_c \) and \( N_f \) are coarse and fine data, respectively; \( T_{ref} \) and \( T_{bin} \) are reference clock period and bin size of TDC, respectively.

In the architecture based on two-level conversion scheme, multiphase generators become the key part of the whole design. As a solution, an array of DLLs is proposed. An important advantage of array of DLLs is that better resolution (less than 100ps) can
easily obtained with either high frequency of reference clock.

Figure 2 shows the architecture of array of DLLs (ADLL) (Christiansen, 1996), (Mota and Christiansen, 1998). Following the functions of ADLL, 140-phase delayed clocks are generated by the array.

The states of phases are then read out as 140-bit acquisition data when a HIT signal arrives. The acquisition data is converted to 8-bit fine data by an encoder. Double counter technique is proposed for improving the reliability of 10-bit coarse data. We propose gray counters instead of binary counters for reducing the power dissipation. The array of DLLs and counters are shared by N channels. Every channel has its readout circuit with a signal of event. A pipeline FIFO circuit is needed for buffering the data coming from N channels. The last time words are output in serial.

3 CIRCUIT DESCRIPTION

3.1 Low-jitter Delay-locked Loop

A full-analog DLL, shown in Figure 3, is selected due to its high performance such as low jitter and wide operational range. The DLL consists of Voltage-controlled delay line, phase detector, charge pump and loop filter. A start-control block is embedded in the circuits to solve the false-lock problem (Chang et al., 2002).

The blocks of DLLs are designed under the consideration of low-jitter characteristic. A current-starved delay cell with DC current source is chosen as our solution. A DC current source, realized by MOS transistors (Mbp and Mbn in Figure 4 (a)), is added to delay cell for reducing the slope of the curve of delay time versus controlled voltage, shown in Figure 4(b). The mismatch in VCDL is an intrinsic problem for DLL design. The unique way to reduce mismatch is using match strategies in layout design such as symmetric, interdigital and common centroid.

A dynamic phase detector (Figure 5 (a)), consisted of two True-single-phase clocking (TSPC) flip-flop, is chosen due to its simple architecture and other advantages such as high operational frequency and no dead zone.
Figure 4: The design of delay cells. (a) Schematic of current-starved delay cell; (b) the characteristic curve of single delay cell.

Figure 5: Phase detector using TSPC flip-flop. (a) Schematic; (b) timing when DLL is locked; (c) Characteristic curve for phase detector.

Figure 6: The proposed charge pump circuit. The charge pump is optimized by adding a feedback circuit to improve the mismatch of charge current and discharge current. The current mismatch problem comes from channel length modulation of Mp0 and Mn0 due to the output voltage (Vc) is changed.

The loop filter is only a capacitor of 100pF. The capacitor is implemented by MOS-capacitor in AMS CMOS 0.35µm technology. Its die size is 90×570µm2.

Figure 6: Proposed charge pump circuit.

3.2 Array of DLLs (ADLL)

Two kinds of DLLs are employed for construction of the array. The time taps of delay cells in both classes of DLLs are $T_m$ and $T_n$ respectively. The bin size of ADLL can be obtained by delay difference of $T_m$ and $T_n$ (where $T_m > T_n$). In order to generate time taps, several functions in the following should be satisfied (Christiansen, 1996), (Mota and Christiansen, 1998).

$$T_{bin} = T_m - T_n \quad (2)$$
$$T_m = T_{clk} / m \quad (3)$$
$$T_n = T_{clk} / n \quad (4)$$
$$F = m / (n - m) \quad (5)$$

where $T_{bin}$ is the bin size of ADLL, which is also described as $\Delta t$; $T_{clk}$ is period of reference clock; $m$ and $n$ are the number of two kinds of DLLs respectively; $F$ is the number of DLL with $n$ delay cells.

In our design, $m$ and $n$ are chosen as 28 and 35 respectively; Then we have $F=4$ and $T_{clk} = 140\Delta t$. $T_m$ and $T_n$ are $5\Delta t$ and $4\Delta t$ respectively. $T_{clk}$ is dependent on the characteristics of delay cells and requirement of $\Delta t$. The architecture of the array of DLLs is shown in Figure 7. One DLL with delay time of $T_m$ is DLL28, while Four DLLs with delay time of $T_n$ are DLL35s (DLL35#0 to DLL35#3). Four reference clocks of DLL35’s are generated by DLL28.

The ADLL consists of a low-jitter DLL with 28 delay cells (DLL28), four low-jitter DLL with 35 delay cells (DLL35), a current-to-voltage conversion block (IVC) and a power-on reset unit (POR). The architecture of ADLL is shown in Figure 7. The low-jitter DLL’s described in section 3.1. The unique difference of DLL28 and DLL35 is the number of VCDL. An IVC is designed for reducing the number of pads and the current mismatch of charge pump in DLLs. The power-on reset unit is employed for enhancing the sensitive of reset function. The sequence of outputs in four DLL35s is disorderly. A lookup table is needed to indicate the relationship between outputs of DLL35s and outputs of ADLL.

3.3 Data Readout Circuits

The Data Readout Circuits of one channel are consisted of fine-data readout unit, coarse-data readout unit and Hit generating circuit. The fine-data readout unit is shown in Figure 8.

140-bit registers should be arranged in the first position for reading out the state of 140 phases.

However, a duty cycle correction circuits should be employed before the registers because the delayed clocks generated by voltage controlled delay
The state of new phases is accurately readout and the acquisition data are easily converted to binary code. Hit signal is processed by this circuit to balance the delay of signal caused by D flip-flop. A 140-bit thermometer-to-binary converter is employed for 8-bit fine data conversion. Another second-level 8-bit registers are set after the conversion process. For recording the coarse data, two-level registers are embedded in the circuits reading out the number of counter, balance the delay of signal. The data in all the channels are readout serially in a cycle of 10µs.

4 PROTOTYPE CHIP AND EXPERIMENTAL RESULTS

A prototype chip of TDC for PET imaging system is designed in AMS 0.35µm CMOS IP4M technology. In this evaluated chip, an array of low-jitter DLLs, double 10-bit gray counters, 3-channel data readout circuits, and a JTAG module are integrated. The chip, which has 88 pads, occupies a die size of 8.4mm². The layout is shown in Figure 8.

The performance of TDC is dependent on the characteristics of DLLs in the array. The operational range of DLLs is measured from 50MHz to 120MHz. The jitter performances at the last output of the DLLs have been evaluated. The rms jitter is less than 7ps and peak-to-peak jitter is less than 20ps. The total static power dissipation of each DLL is about 4mW when the charge and discharge current of charge pump is 40µA. The total power of TDC is about 50mW while the total static power is less than 10mW.

Figure 9(a) shows the post simulation result of conversion curve of prototype chip in three clock periods. The time taps is generated by random emission algorithm. The differential nonlinearity shown in Figure 9(b) is ±0.1LSB. The integral nonlinearity is ±0.1LSB. The result is measured with code density test by post simulation. The DNL of last 10 data (from 129 to 139) is larger than others due to the layout mismatch. It is indicated that the proposed TDC has good performances on high resolution, wide measure range, and low power dissipation.

The overall performances of our prototype chip are shown in Table 2. It is indicated that the TDC using two-level conversion architecture based on array of DLL can easily achieve smaller timing resolution by using either a faster technology. Moreover, wide dynamic range of measurement and low power performances are obtained.

![Figure 7: Topology of Array of DLL.](image)

![Figure 8: Layout of a prototype chip of TDC based on an array of DLLs.](image)

![Figure 9: Experimental Results. (a) Conversion curve of TDC in three clock period,(b) Differential nonlinearity of TDC prototype chip.](image)
5 CONCLUSIONS

This paper describes the design of a high-resolution multi-channel TDC applied for biomedical imaging applications. A two-level scheme based on array of DLLs has been successfully applied for TDC. A prototype chip of 3-channel TDC for PET Imaging systems is designed and fabricated in 0.35µm CMOS IP4M technology. The bin size of TDC is reduced to 71ps. From the analysis of results, the array of DLLs has low-jitter performances and the TDC has some advantages on high resolution, wide measure range and low power.

For further development, the circuits will be extended to 64-channel TDC for small animal PET imaging systems. This kind of TDC can also be widely used for particle life detection in high energy physics and space applications. However, the array of DLLs occupies large die size. Tradeoff between bin size of TDC and die size should be considered for different applications.

Table 1: Overall performances of the prototype chip.

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<td>Array of DLLs</td>
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<td>CMOS 0.35µm</td>
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<td>244ps</td>
<td>312.5ps</td>
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REFERENCES


